

High-level Behavioral Models With Time-Domain Noise

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Motivation

- Lab-measured noise is usually greater than predicted from small-signal noise simulation
 - Small-signal simulation is appropriate for linear, time-invariant (LTI) systems
 - Switched capacitor (SC) circuits and RF mixers are not LTI
- Discrete-time nature of SC circuits such as sampling mixers aliases wide-band noise into the pass-band.
- This aliased noise does not appear in small-signal noise sims.
- Estimation methods exist:
 - "Design-Oriented Estimation of Thermal Noise in Switched-Capacitor Circuits", R. Schreier
- Transient noise simulation, available in Cadence's Spectre simulator, inserts time-domain noise generators into device models.
 - Noise folding due to sampling occurs naturally due to time-domain nature of simulation
 - Appropriate for circuit simulation of relatively small circuits
 - Run time takes too long for larger systems such as a radio receiver front end.
- Idea: Add time-domain noise generators to faster-running AMS behavioral models**
 - Noise folding occurs naturally
 - Simulate large, high-speed circuits
 - See the system level effect of thermal noise
- Algorithms for coding of transient noise generators can be found in
 - "Transient analysis of thermal noise on switch cap circuit", P. Chiu, C. Lee

Wide-Band Noise

- Resistor noise: $N_R = \sqrt{4k_B T R \cdot BW}$, V_{RMS}
- Resistors inject wide-band noise into a circuit.
- A reasonable definition of wide-band (BW in the above formula) is 10 times the system's bandwidth of interest.
- Since a sampled system can only discriminate frequencies up to half the sampling rate, instead of 10X, we sample the noise generator at 20 times the system bandwidth.
- For a 2 GHz system we sample at 40 GHz, and wide-band noise is defined out to 20 GHz.
- For $R = 50$ Ohms, $T = 300$ K and $BW = 20$ GHz $N_R = \sqrt{4 \cdot 1.38 \cdot 10^{-23} \cdot 300 \cdot 50 \cdot 20 \cdot 10^9} = 129 \mu V_{RMS}$
- General Approach:
 - Use a circuit simulator to find the input- or output-referred RMS noise voltage of a wide-band subcircuit
 - Assign RMS noise voltage to a noise generator instantiated in the model

Time-domain Wide-Band Noise Verilog-AMS Code

```

inout Z1, Z2; // Noise generator input, output

parameter real RMS_noise_voltage = 129e-6; // Assigned noise voltage
parameter real System_Bandwidth = 2e9; // in 2 GHz system
parameter integer SEED = 0; // Zero results in different noise sequences in
// each run. For identical noise each run, use SEED > 0, but if so, each noise generator instance
// must have a different SEED value, of course, or each noise generator will output the same waveform.

real ts; // Noise generator sample time
integer seedx; // The actual seed used by the random number generator
real vn; // Random number sample

initial begin
  ts = 1/(20*System_Bandwidth); // Set the sampling time. Noise spectrum is 10 * System_Bandwidth
end

analog begin
  @(initial_step("static")) begin
    seedx = (SEED == 0) ? $random:SEED; // Either a random or fixed seed for random number generator.
    vn = 0.0; // Initial noise sample.
  end

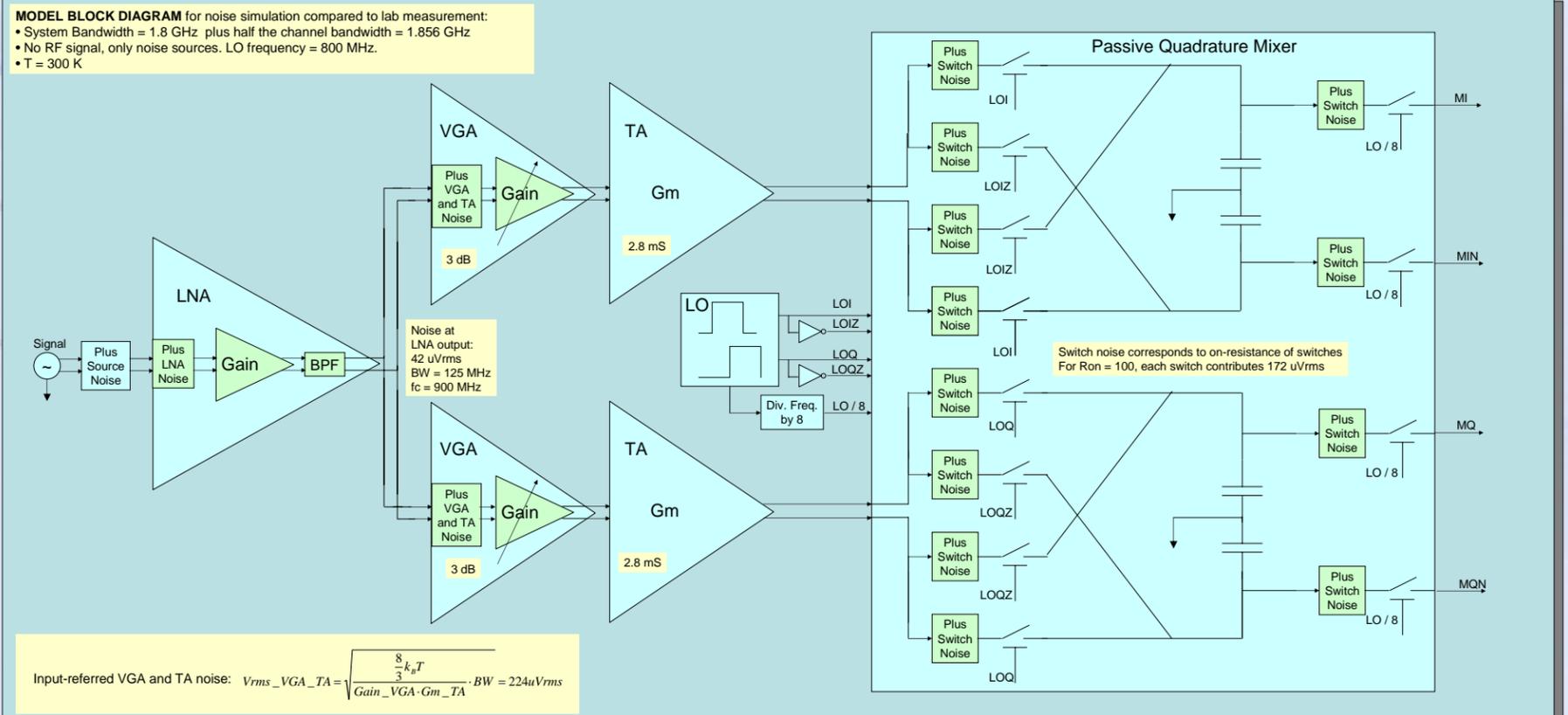
  @(timer(0,ts)) begin // Generate a random real number
    vn = RMS_noise_voltage * $rdist_normal(seedx,0,1.0);
  end

  V(Z1,Z2) <+ vn; // Assign it to the voltage across inouts
end
    
```

Narrow-Band Noise

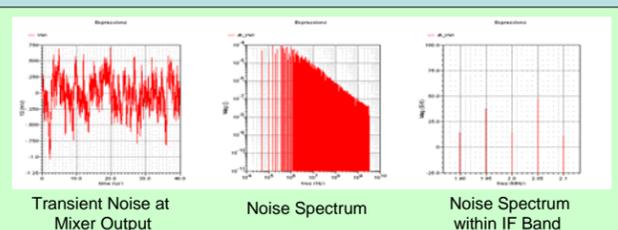
- An LNA has narrow-band noise at its output. Its model:
 - Amplifies its input (including noise) by its gain. (Including parameterized distortion factors.)
 - Adds its own noise (Instantiates a wide-band noise generator.)
 - Bandpass-filters the amplified input noise and its own noise.
- When validating the model, compare its output to the expected output noise level and spectrum, and adjust the BPF gain and filter characteristics accordingly

Application: GSM Receiver Front End with Switched-Capacitor Passive Mixer



Noise Simulation, Measured Results and Conclusions

- APPROACH:**
- Mixer output VMI = MI - MIN plotted and post-processed
 - Discrete Fourier analysis performed with Waveform Calculator and plotted
 - 40 us transient simulation yields 50 kHz frequency resolution
 - Simulation run time: 33 minutes, versus several hours for Pnoise.
 - RMS noise voltage in IF band, (corresponding to lab measurements), calculated from frequency bins in 200 kHz band centered at 2 MHz



Comparison of Simulation to Measurement			
Signal	PNOISE Simulated Results	Noise Generator Simulated Results	Laboratory Measured Results
Mixer Output	27 uVrms	64.4 uVrms	119 uVrms

- CONCLUSIONS:**
- Behavioral models can be written to inject transient noise into their inputs or outputs
 - Transient noise generator simulation is faster and more accurate than small-signal noise simulation of switched-capacitor systems
- LESSONS LEARNED:**
- A valuable method for evaluating the system-level effects of thermal noise
 - Further investigation is required to find the source of discrepancy between simulated and measured output noise such as
 - Transient noise generator levels may have been based on overly optimistic device level noise models
 - Lab-measurements may include interference as well as thermal noise
 - Possible mistake in de-embedding of device from signal source, matching, buffer, instruments
- Contact Robert.Peruzzi@Infineon.com for further behavioral modeling information or access to source code for these models.